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# Femtosecond laser-matter interaction of tungsten carbide

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The purpose of this research is to investigate the femtosecond laser-matter interaction for a tungsten carbide with 10% of cobalt. A femtosecond laser (1030 nm) with a pulse duration of 400 fs have been used for this study. For cumulated fluences between 1.4 and 4  $J/cm^2$ , Laser-Induced Periodic Surface Structures (LIPSS) could be produced with a low ablation rate. LIPSS had a spatial period of 665 nm and an amplitude of 225 nm. The a-thermal ablation threshold fluence have been found to be from 0.35 to 11  $J/cm^2$  in cumulated fluence for a range between 1 to 100 pulses. Thus dimples could be fabricated without any thermal effects. In addition, incubation coefficient and optical penetration depth of tungsten carbide were determined. They are equal to 0.79 and 19 nm respectively.

#### **1. INTRODUCTION**

For the last two decades, ultrashort pulsed lasers have been beneficial to handle issues in many applications from manufacturing, military, aerospace and medical industries. Nowadays, this technique is more and more employed to tune the surface properties of a material such as wettability and tribological behavior [1]. In this work, we used laser surface structuring for improving cutting results on tungsten carbide workpieces for turning applications. The desired scope is to decrease both abrasive wear and adhesion on workpieces while machining stainless steel or aluminum alloy. Nevertheless, the interaction of laser pulses with tungsten carbide material has been tackled by only few researchers. Dumitru et al. [2-5] determined the threshold fluence for texturation regime which permits to create nanoscale structures named LIPSS or "ripples". Pfeiffer [6], Calderón Urbina [7] and Neves [8] determined the a-thermal ablation threshold fluence using respectively a femtosecond, picosecond and nanosecond-lasers. For a purpose of

improving workpieces made of tungsten carbide by adapting their tribological and physicochemical properties, we need to determine precisely these threshold fluences for performing desired double-scale structures on samples. In fact, we aim to produce nano- scale structures (LIPSS), micro- scale structures and a combination of nano- and micro-scale structures on tungsten carbide workpieces. Knowing the laser-matter interaction is crucial before considering laser material micromachining process. We are proposing to investigate the behavior of tungsten carbide with 10% of cobalt under femtosecond laser pulses at variable peak fluence and number of laser pulses. We will identify the laser-matter interaction regimes for the selected material and give the mapping of fluence domains corresponding to each regime. We will also determine the incubation coefficient and optical penetration depth for tungsten carbide, parameters which are indexed only by one author in literature [7].

#### 2. MATERIALS AND METHODS

The equipment used for laser experiments was a laser source (Tangor HP model from Amplitude Systems®, France) with an average power of 100 W, a maximum pulse energy of 500  $\mu$ J at a wavelength of 1030 nm and a variable repetition rate adjustable from one shot to 2 MHz. The minimum pulse duration is equal to 400 fs. We used a Gaussian beam which had a radius of  $16.67\pm0.5\,\mu m$  measured by a beam analyzer. The studied samples were made of tungsten carbide with 10% of cobalt binder and with an average grain size of 0.7 µm. The samples were mirror-polished with diamond particles (from 9 µm down to 3 µm) and washed in an ultrasonic cleaner with ethanol for 5 min before the laser machining. The resulting surface roughness was Ra = 60 nm and Rz = 80 nm. A static matrix of impacts has been performed using different values of peak fluence (from 0.028 to 5.6 J/cm<sup>2</sup>) and various number of pulses (from 1 to 100) at a repetition rate of 1 kHz. Dimples were examined using a scanning electron microscope (SEM-FEI Quanta™ 450 W), an atomic force microscope (AFM) and a confocal microscope (Alicona Infinite focus®). These different techniques permitted either to measure dimples depth and diameter, or to reveal the morphology of the dimples, and to observe and characterize the Laser-Induced Periodic Surface Structures (LIPSS).

#### **3. THEORY/CALCULATION**

For a Gaussian beam profile shown in Figure 1.a), the spatial variation of laser fluence can be expressed as [9]:

$$F(r) = F_0 \cdot \exp\left(-\frac{2r^2}{\pi\omega_0^2}\right) \quad , \quad F_0 = \frac{2E}{\pi\omega_0^2}$$
(1)

where *r* is the distance from the laser beam center,  $F_0$  is the peak fluence at the center (r = 0),  $\omega_0$  is the focused beam radius at  $1/e^2$  of  $F_0$ , and *E* is the incident laser pulse energy. In case of *N* static impacts, when the peak fluence  $F_0$  is above the ablation threshold fluence  $F_{th}(N)$ , a dimple appears by ablation process as presented in Figure 1.b).



**Fig. 1. a)** Schematic of Gaussian beam profile, **b)** SEM image of crater generated on tungsten carbide material using a peak fluence  $F_0 = 2.6$  J/cm<sup>2</sup> and N = 100 pulses, **c)** 2D profile of produced dimple (D = diameter,  $h_N$  = depth).

The diameter of ablation dimple shown in Figure 1.c) can be expressed as [9, 10]:

$$D^{2} = 2\omega_{0}^{2} \ln(\frac{F_{0}}{F_{th}(N)})$$
<sup>(2)</sup>

where  $F_{th}(N)$  is the ablation threshold fluence of N pulses. This linear dependence between  $D^2$  and the logarithm of peak fluence permits to accurately calculate the focused beam radius  $\omega_0$  and to determine the Npulses a-thermal ablation threshold fluence  $F_{th}(N)$ . This threshold fluence value is decreasing with the number of pulses as after multiple laser shots in a same area, the surface is modified and its optical properties change. An accumulation of energy occurs in the material which causes an incubation effect [11, 12]. This reaction can be expressed by the relation between the a-thermal ablation threshold fluence for N pulses  $F_{th}(N)$  and the a-thermal ablation threshold fluence for 1 pulse  $F_{th}(1)$  as:

$$F_{th}(N) = F_{th}(1) \cdot N^{\xi - 1}$$
(3)

where  $\xi$  is the response of the material to cumulative ablation shots. When  $\xi = 1$ , the threshold fluence is independent of the number of pulses and there is no incubation effect. When  $\xi < 1$ , some residual energy is left in the material between each pulse, thus decreasing the a-thermal ablation threshold fluence while increasing number of pulses. For the a-thermal ablation regime, the ablation depth depends on the optical penetration depth  $\alpha^{-1}$ , where  $\alpha$  is the absorption coefficient of the material at the given laser wavelength. The ablation depth for 1-pulse is given by [13]:

$$h_1 = \alpha^{-1} . \ln(\frac{F_0}{F_{th}(1)})$$
 (4)

The ablation depth  $h_N$  for N pulses shown in Figure 1.c) is expressed as:

$$h_N = N. \, \alpha^{-1}. \ln(\frac{F_0}{F_{th}(N)})$$
(5)

#### 4. RESULTS AND DISCUSSION

As defined in Equation 2, the relationship between the measured dimple diameter squared ( $D^2$ ) and the logarithm of peak fluence can be used to deduce the laser beam spot radius  $\omega_0$  and a-thermal ablation threshold fluence for *N* pulses. Figure 2 shows the relationship between the square of the dimple diameter and the logarithm of peak fluence for dimples produced by 10, 50 and 100 pulses at a repetition rate of 1 kHz. Applied peak fluences were calculated using measured waist size of the focused beam using Equation 1. Dimple's diameter were measured using confocal microscope (Alicona Infinite focus<sup>®</sup>). The laser beam spot radius  $\omega_0$  is calculated from the slope of the line of best fit to the data in Figure 2 for each N pulses. An average  $\omega_0$  is found to be  $15.75 \pm 0.8 \ \mu\text{m} \ \mu\text{m}$  which is close to the measured beam spot size ( $16.67 \pm 0.5 \ \mu\text{m}$ ). Once beam size is calculated from experimental analysis, from this point forward, applied peak fluence will be calculated using this new value of beam radius.

As the a-thermal ablation threshold fluence changes with number of pulses applied to the same spot, by an extrapolation to  $D^2 = 0$ ,  $F_{th}(N)$  for

each *N* can be determined. From Figure 2, a-thermal ablation threshold fluences were found to be  $0.19 \text{ J/cm}^2$ ,  $0.14 \text{ J/cm}^2$  and  $0.11 \text{ J/cm}^2$  for *N* = 10, 50 and 100 respectively.



**Fig. 2.** Squared diameters of dimples as a function of the logarithm of laser peak fluence for N = 10, 50, 100

Figure 3 shows the evolution of a-thermal ablation threshold fluence as a function of number of pulses. For a-thermal ablation regime, the range of the threshold fluence is found to be between 0.11 to  $0.35 \text{ J/cm}^2$  from N = 100 to 1 pulses, as seen on Figure 3. It corresponds to a range of 0.35 to 11 J/cm<sup>2</sup> in cumulated fluence ( $N \times F_0$ ). A-thermal ablation threshold fluence for a single-pulse is found to be  $F_{th}(1) = 0.35 \text{ J/cm}^2$ .

Among the few works giving results about the a-thermal ablation domain and thresholds, Neves et al. found the upper limit of the range of a-thermal ablation zone to be at 22.92 J/cm<sup>2</sup> in cumulated fluence starting their investigations from 3.82 J/cm<sup>2</sup> [8] whereas Tan et al. worked in the range between 0.49 to 4.11 J/cm<sup>2</sup> without defining these values as the limits of the ablation domain [14]. More complete work have been published by Dumitru et al. [4, 5], Pfeiffer [6] and Calderón Urbina [7]. Dumitru and Pfeiffer found the lower limit around 0.4 J/cm<sup>2</sup> and Calderón Urbina around 0.2 J/cm<sup>2</sup> both for a single-pulse. The variations can be explained, in one hand, by the difference of pulse duration applied, which is 10 ps for Calderón Urbina and about 100 fs for Pfeiffer and Dumitru. On the other hand, it can also be due to wavelength employed during experiments, which is 1064 nm for Calderón Urbina et al., 532 nm for Neves et al. and around 775-800 nm for the other authors. However the order of magnitude of these values are close to the measured one in the present work notwithstanding the different composition of studied materials.



Fig. 3. Threshold fluence as a function of number of pulses.

Incubation coefficient  $\xi$  has been determined from slope of the line of best fit to the data in Figure 4, and found to be equal to 0.79. According to Calderón Urbina et al., the incubation coefficient for tungsten carbide is given as 0.85 for a matrix with 12% of cobalt and a grain size of 0.5  $\mu m$  [7].



Fig. 4. Accumulation of ablation threshold versus number of pulses.

According to Equation 5, when plotting depth of ablated dimples as a function of the logarithm of peak fluence  $F_0$  which is calculated using the new value of beam spot size (15.75 µm), as illustrated on Figure 5, optical penetration depth ( $\alpha^{-1}$ ) can be determined. Dimple's depth were measured using a confocal microscope (Alicona Infinite focus<sup>®</sup>). We

found an average optical penetration depth equal to  $19 \pm 2.8$  nm. According to Calderón Urbina and Pfeiffer, optical penetration depth for tungsten carbide is equal to 22.5 nm measured with different lasers and carbide compositions [7].



**Fig. 5.** Ablation depth  $h_N$  versus the logarithm of peak laser fluence for N = 20, 50, 70, 100.

Figure 6 shows the relationship between dimple depth and number of pulses for dimples produced at variable peak fluence  $F_{\theta}$  (using  $\omega_{\theta} = 15.75 \,\mu$ m) for a fixed repetition rate of 1 kHz. There is a linear relation between ablation depth and number of pulses at different peak fluences.



**Fig. 6.** Ablation depth  $h_N$  versus the number of pulses *N* for  $F_0$  = 0.45, 0.9, 1.6, 3.4, 5.6 J/cm<sup>2</sup>

No structural damage is observed on the material at peak fluences below  $0.22 \text{ J/cm}^2$  from 1 to 100 pulses. Then, a damaged impact appears for 1-pulse at a peak fluence of  $0.22 \text{ J/cm}^2$ . So, the first interaction threshold fluence for one pulse is between  $0.11-0.22 \text{ J/cm}^2$ . According to Dumitru et al., this range is between 0.08 to  $0.14 \text{ J/cm}^2$  for one pulse for tungsten carbide samples with 6% and 10% of cobalt binder [4, 5].

The LIPSS appear above a threshold value of fluence. Figure 7 displays LIPSS with low ablation rate produced at a peak fluence of 0.2 J/cm<sup>2</sup> and a number of pulses of 20. In our matrix, periodic LIPSS appeared from  $F_0 = 0.2 \text{ J/cm}^2$  for N = 7, with a mean periodicity of 665 nm and an average height of 225 nm measured using AFM technique. 2D profile of LIPSS is presented on Figure 8. These ripples had a period equal to approximately 0.6× $\lambda_{\text{laser}}$ . In the literature, this kind of ripples is called coarse ripples or low spatial frequency (LSF-LIPSS) [15]. The orientation of LIPSS is perpendicular to the polarization direction of the laser beam. From AFM analysis, we could determine the range of texturation regime (LIPSS generation zone) without digging. This range is between 1.4 to 4 J/cm<sup>2</sup> which is a cumulated fluence ( $N \times F_0$ ) for a peak fluence of 0.2 J/cm<sup>2</sup> and a number of pulses varying from 7 to 20 pulses. For a single-pulse, threshold peak fluence of texturation regime would be between 0.22 and 0.35 J/cm<sup>2</sup>. According to Dumitru et al., the range of texturation regime is between 0.4 to 2.8 J/cm<sup>2</sup> for a tungsten carbide of 10% of cobalt and a grain size of 0.5 µm [5]. Once threshold fluences for each regime were established, laser-matter interaction domain map for tungsten carbide can be drawn, as shown on Figure 9.



**Fig. 7.** SEM image of LIPSS on tungsten carbide ( $F_0 = 0.2 \text{ J/cm}^2$ ; N = 20).



**Fig. 8.** Characterization of produced LIPSS using  $F_0 = 0.3 \text{ J/cm}^2$ ; N = 20: **a)** AFM image 5x5  $\mu$ m<sup>2</sup>, **b)** 2D profile along LIPSS.



#### 5. CONCLUSIONS

We have investigated the laser matter-interaction for tungsten carbide with femtosecond laser for multiple number of pulses and different fluence values. The main conclusions can be summerized as follows:

(1) Three regimes were identified which correspond to: low interaction zone, LIPSS zone and a-thermal ablation zone. Figure 9 is intended to show these three range zones.

(2) Ripples could be produced starting from N = 7 at a peak fluence of 0.2J/cm<sup>2</sup>. They were perpendicular to the polarization of the laser beam and have a period equivalent to  $0.6 \times \lambda_{\text{laser}}$ .

(3) The single pulse threshold fluence for a-thermal ablation was determined and is equal to  $0.35 \text{ J/cm}^2$  which is close to the values of Dumitru and Pfeiffer.

(4) Incubation coefficient of tungsten carbide is found to be 0.79 in agreement with Calderón Urbina's postulated value.

(5) Optical penetration depth of tungsten carbide has been determined and found equal to 19 nm in accordance with Calderón Urbina and Pfeiffer's results using different tungsten carbide grades.

It is the first time that all the laser-matter parameters for generating ripples or femtosecond laser-matter ablation on tungsten carbide have been measured and communicated to worldwide scientific community.

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Disclosures. The authors declare no conflicts of interest.

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